

#### Features:

- SMD plastic package
- · High photo sensitivity
- Fast response time
- · Choice of four lead configurations
- IR transmissive plastic package



### **Description:**

Each device in this series is an NPN silicon phototransistor mounted in an opaque plastic SMD package, with an integral molded lens that enables a narrow acceptance angle and a higher collector current than devices without a lense.

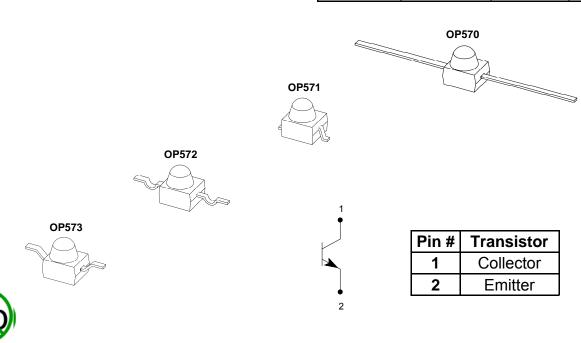
The **OP570** series has four lead configurations and is compatible with most automated mounting equipment. *The OP570* series is mechanically and spectrally matched to the OP270 series infrared LEDs.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

#### **Applications:**

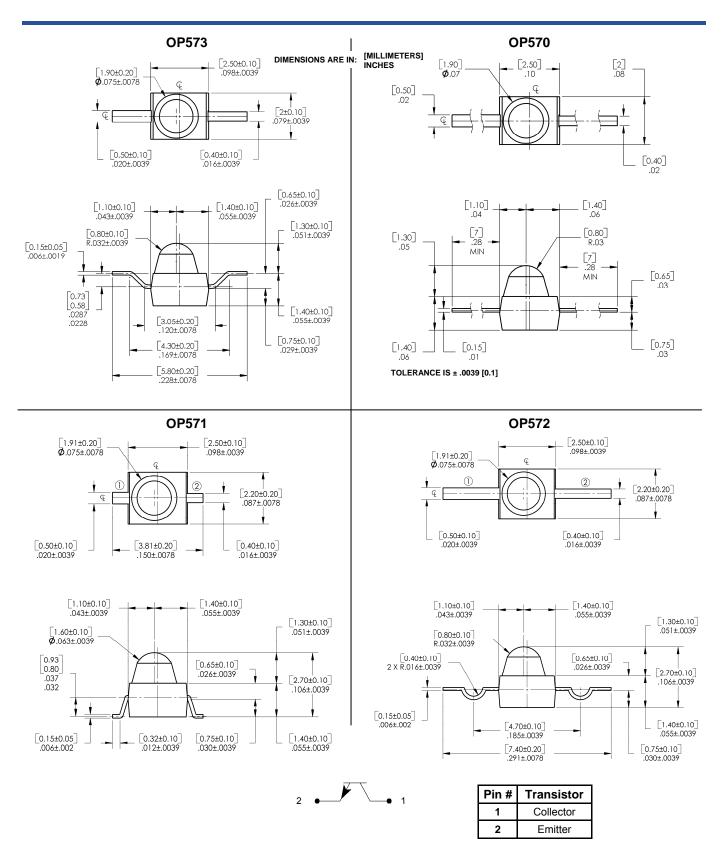
- · Non-contact position sensing
- Datum detection
- Machine automation
- Optical encoders
- IrDA
- Reflective and transmissive sensors

| Ordering Information |                  |                  |                |  |  |  |
|----------------------|------------------|------------------|----------------|--|--|--|
| Part Number          | Sensor           | Viewing<br>Angle | Lead<br>Length |  |  |  |
| OP570                |                  | 25°              | Axial          |  |  |  |
| OP571                | Phototransistor  |                  | Gull Wing      |  |  |  |
| OP572                | FIIOLOLIANSISIOI |                  | Yoke           |  |  |  |
| OP573                |                  |                  | Rev. Gull      |  |  |  |



RoHKS







### Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise noted)

| Storage Temperature Range   | -40° C to +85° C      |
|---|-----------------------|
| Operating Temperature Range   | -25° C to +85° C      |
| Collector-Emitter Voltage   | 30 V                  |
| Emitter-Collector Voltage   | 5 V                   |
| Collector Current   | 20 mA                 |
| Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron] | 260° C <sup>(1)</sup> |
| Power Dissipation   | 130 mW <sup>(2)</sup> |

#### Notes

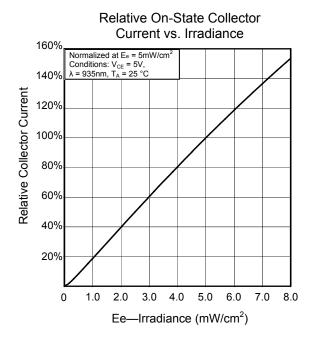
- 1. Solder time less than 5 seconds at temperature extreme.
- 2. Derate linearly at 2.17 mW/° C above 25° C.

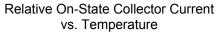
#### Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

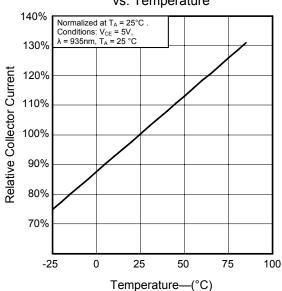
| SYMBOL               | PARAMETER                           | MIN | TYP | MAX | UNITS | TEST CONDITIONS   |  |  |
|----------------------|-------------------------------------|-----|-----|-----|-------|---|--|--|
| Input Diode          |                                     |     |     |     |       |   |  |  |
| I <sub>C (ON)</sub>  | On-State Collector Current          | 2.5 | 1   | -   | mA    | $V_{CE} = 5.0 \text{ V}, E_{E} = 5.0 \text{ mW/cm}^{2}$ (1) |  |  |
| $V_{CE(SAT)}$        | Forward Voltage                     | -   | -   | 0.4 | V     | $I_C = 100 \mu A, E_E = 2.0 \text{ mW/cm}^{2 (1)}$          |  |  |
| I <sub>CEO</sub>     | Reverse Current                     | -   | -   | 100 | nA    | $V_{CE} = 5.0 \text{ V}, E_E = 0^{(2)}$                     |  |  |
| $V_{BR(CEO)}$        | Wavelength at Peak Emission         | 30  | ı   | -   | V     | I <sub>C</sub> = 100 μA                                     |  |  |
| V <sub>(BR)ECO</sub> | Emission Angle at Half Power Points | 5   | -   | -   | V     | I <sub>E</sub> = 100 μA                                     |  |  |

#### Notes:

- 1. Light source is an unfiltered GaAl LED with a peak emission wavelength of 935nm and a radiometric intensity level which varies less than 10% over the entire lens surface of the phototransistor being tested.
- 2. To calculate typical collector dark current in  $\mu$ A, use the formula  $I_{CEO} = 10^{(0.04 \text{ Ta-3.4})}$  where Ta is the ambient temperature in ° C.





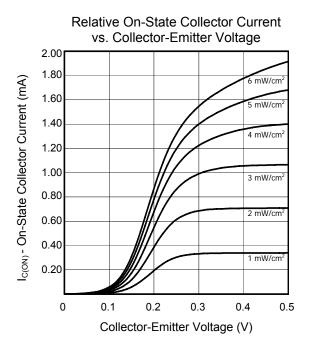


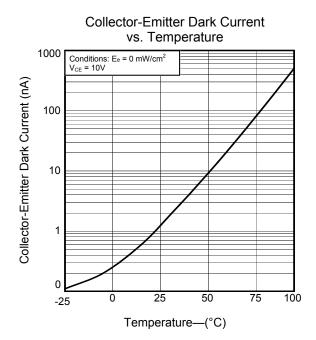


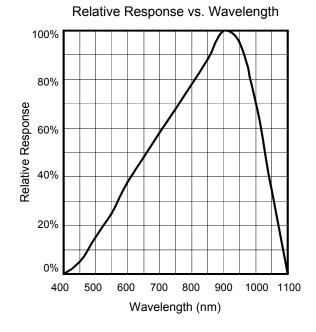
Relative Response vs.
Angular Position

100%
80%
60%
20%
20%
-90 -60 -30 0 30 60 90

Angular Position (Degrees)







# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Photo IC Sensors category:

Click to view products by TT Electronics manufacturer:

Other Similar products are found below:

HOA6991-500 OPL800 OPL801-OC OPL810 OPL811-OC OPL820 OPB608-001 PT91-21C OPL536A OPL560 OPL560-OCA LTDL-TA25B-T ADPD2210ACPZ-R7 OPL800-OC OPL801 OPL813-OC OPL820-OC SD2410-101 ADPD2211ACPZ-RL ADPD2211ACPZ-R7 ADPD2214ACPZ-R7 SD5600-001 SD5610-001 SD5630-001 SD5630-002 SDP8304-301 SDP8600-003 SDP8601-001 SDP8601-002 SDP8610-003 SDP8611-001 SDP8611-002 SDP8611-003 SDP8614-301 LTDL-TA16A QSE159 QSE259 OP572 OPB892N55Z OPB390N55Z OPB854B2 OPB870T11 OPB877N55 OPB861N51 OPB962L51 OPB981L11Z OPB963L51 OPL530 OPL530-OC OPL531A